Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:

Glass

Overall Length:

0.350 inches

Terminal Length:

0.975 inches

Overall Diameter:

0.145 inches

Mounting Method:

Terminal

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

200.0 reverse voltage, peak and 1.1 on voltage, forward voltage drop, dc

Current Rating Per Characteristic:

1.20 amperes forward current, average absolute and 3.00 amperes forward current, average peak

Capacitance Rating In Picofarads:

320.0

Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius ambient air

Test Data Document:

84347-181-655 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.;

excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

2 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0